

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 7,052,623 B1  
APPLICATION NO. : 09/581663  
DATED : May 30, 2006  
INVENTOR(S) : Volker Becker et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 1, line 24, change "Disadvantages" to --Disadvantageous--

Column 1, line 33, change "can act very" to --can act very corrosively.--

Column 3, line 12, change "...OF THE DRAWING" to --OF THE DRAWINGS--

Column 6, line 13, change "in which the silicon" to --in which the silicon--

Column 7, line 16, change "DE 42 41 045, and" to --DE 42 41 045, an--

Column 7, line 32, change "remain essentially" to --remain essentially unchanged.--

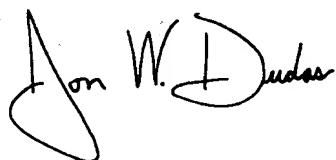
Column 11, line 54, change "etching process than etching" to --etching process then etching--

Column 12, line 40, change "layer section 912)" to --layer section (12)--

Column 16, line 18, change "is formed thermally grown silicon" to --is formed from thermally grown silicon--

Signed and Sealed this

Twenty-second Day of May, 2007



JON W. DUDAS  
*Director of the United States Patent and Trademark Office*